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"Embedded - Microcontrollers" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "<u>Embedded -</u> <u>Microcontrollers</u>"

Details

Product Status	Not For New Designs
Core Processor	CIP-51 8051
Core Size	8-Bit
Speed	50MHz
Connectivity	I ² C, SMBus, SPI, UART/USART
Peripherals	Brown-out Detect/Reset, POR, PWM, WDT
Number of I/O	20
Program Memory Size	64KB (64K x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	4.25K x 8
Voltage - Supply (Vcc/Vdd)	2.2V ~ 3.6V
Data Converters	A/D 12x10/12b SAR; D/A 2x12b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 125°C (TA)
Mounting Type	Surface Mount
Package / Case	24-WFQFN Exposed Pad
Supplier Device Package	24-QFN (4x4)
Purchase URL	https://www.e-xfl.com/product-detail/silicon-labs/efm8bb31f64i-b-4qfn24r

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Address: Room A, 16/F, Full Win Commercial Centre, 573 Nathan Road, Mongkok, Hong Kong

EFM8BB3 Data Sheet Ordering Information

Ordering Part Number	Flash Memory (kB)	RAM (Bytes)	Digital Port I/Os (Total)	Voltage DACs	ADC0 Channels	Comparator 0 Inputs	Comparator 1 Inputs	Pb-free (RoHS Compliant)	Temperature Range	Package
EFM8BB31F64G-B-QSOP24	64	4352	21	4	13	6	7	Yes	-40 to +85 °C	QSOP24
EFM8BB31F32G-B-QFN32	32	2304	29	2 ¹	20	10	9	Yes	-40 to +85 °C	QFN32
EFM8BB31F32G-B-QFP32	32	2304	28	2 ¹	20	10	9	Yes	-40 to +85 °C	QFP32
EFM8BB31F32G-B-QFN24	32	2304	20	2 ¹	12	6	6	Yes	-40 to +85 °C	QFN24
EFM8BB31F32G-B-QSOP24	32	2304	21	2 ¹	13	6	7	Yes	-40 to +85 °C	QSOP24
EFM8BB31F16G-B-QFN32	16	2304	29	2 ¹	20	10	9	Yes	-40 to +85 °C	QFN32
EFM8BB31F16G-B-QFP32	16	2304	28	2 ¹	20	10	9	Yes	-40 to +85 °C	QFP32
EFM8BB31F16G-B-QFN24	16	2304	20	2 ¹	12	6	6	Yes	-40 to +85 °C	QFN24
EFM8BB31F16G-B-QSOP24	16	2304	21	2 ¹	13	6	7	Yes	-40 to +85 °C	QSOP24
EFM8BB31F64I-B-QFN32	64	4352	29	4	20	10	9	Yes	-40 to +125 °C	QFN32
EFM8BB31F64I-B-QFP32	64	4352	28	4	20	10	9	Yes	-40 to +125 °C	QFP32
EFM8BB31F64I-B-QFN24	64	4352	20	4	12	6	6	Yes	-40 to +125 °C	QFN24
EFM8BB31F64I-B-QSOP24	64	4352	21	4	13	6	7	Yes	-40 to +125 °C	QSOP24
EFM8BB31F32I-B-QFN32	32	2304	29	2 ¹	20	10	9	Yes	-40 to +125 °C	QFN32
EFM8BB31F32I-B-QFP32	32	2304	28	2 ¹	20	10	9	Yes	-40 to +125 °C	QFP32
EFM8BB31F32I-B-QFN24	32	2304	20	2 ¹	12	6	6	Yes	-40 to +125 °C	QFN24
EFM8BB31F32I-B-QSOP24	32	2304	21	2 ¹	13	6	7	Yes	-40 to +125 °C	QSOP24
EFM8BB31F16I-B-QFN32	16	2304	29	2 ¹	20	10	9	Yes	-40 to +125 °C	QFN32
EFM8BB31F16I-B-QFP32	16	2304	28	2 ¹	20	10	9	Yes	-40 to +125 °C	QFP32
EFM8BB31F16I-B-QFN24	16	2304	20	2 ¹	12	6	6	Yes	-40 to +125 °C	QFN24
EFM8BB31F16I-B-QSOP24	16	2304	21	2 ¹	13	6	7	Yes	-40 to +125 °C	QSOP24

1. DAC0 and DAC1 are enabled on devices with 2 DACs available.

3. System Overview

3.1 Introduction

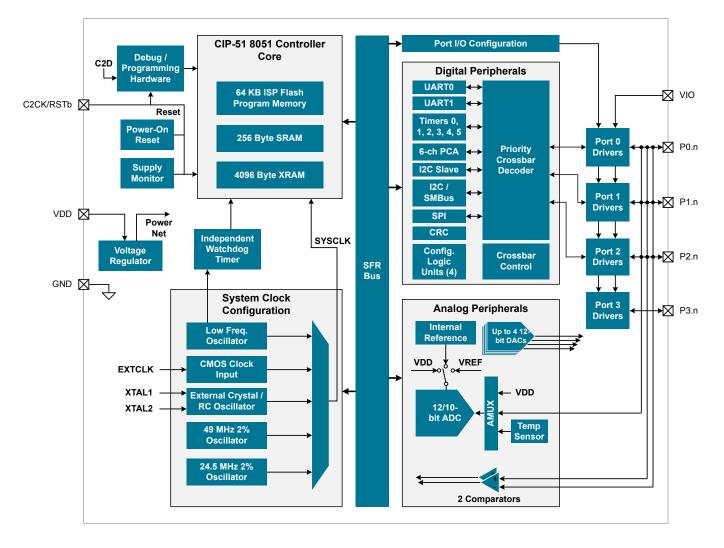


Figure 3.1. Detailed EFM8BB3 Block Diagram

I2C Slave (I2CSLAVE0)

The I2C Slave interface is a 2-wire, bidirectional serial bus that is compatible with the I2C Bus Specification 3.0. It is capable of transferring in high-speed mode (HS-mode) at speeds of up to 3.4 Mbps. Firmware can write to the I2C interface, and the I2C interface can autonomously control the serial transfer of data. The interface also supports clock stretching for cases where the core may be temporarily prohibited from transmitting a byte or processing a received byte during an I2C transaction. This module operates only as an I2C slave device.

The I2C module includes the following features:

- Standard (up to 100 kbps), Fast (400 kbps), Fast Plus (1 Mbps), and High-speed (3.4 Mbps) transfer speeds
- · Support for slave mode only
- · Clock low extending (clock stretching) to interface with faster masters
- · Hardware support for 7-bit slave address recognition
- Transmit and receive FIFOs (two byte) to help increase throughput in faster applications
- · Hardware support for multiple slave addresses with the option to save the matching address in the receive FIFO

16-bit CRC (CRC0)

The cyclic redundancy check (CRC) module performs a CRC using a 16-bit polynomial. CRC0 accepts a stream of 8-bit data and posts the 16-bit result to an internal register. In addition to using the CRC block for data manipulation, hardware can automatically CRC the flash contents of the device.

The CRC module is designed to provide hardware calculations for flash memory verification and communications protocols. The CRC module supports the standard CCITT-16 16-bit polynomial (0x1021), and includes the following features:

- Support for CCITT-16 polynomial
- Byte-level bit reversal
- · Automatic CRC of flash contents on one or more 256-byte blocks
- · Initial seed selection of 0x0000 or 0xFFFF

Configurable Logic Units (CLU0, CLU1, CLU2, and CLU3)

The Configurable Logic block consists of multiple Configurable Logic Units (CLUs). CLUs are flexible logic functions which may be used for a variety of digital functions, such as replacing system glue logic, aiding in the generation of special waveforms, or synchronizing system event triggers.

- · Four configurable logic units (CLUs), with direct-pin and internal logic connections
- Each unit supports 256 different combinatorial logic functions (AND, OR, XOR, muxing, etc.) and includes a clocked flip-flop for synchronous operations
- · Units may be operated synchronously or asynchronously
- · May be cascaded together to perform more complicated logic functions
- · Can operate in conjunction with serial peripherals such as UART and SPI or timing peripherals such as timers and PCA channels
- · Can be used to synchronize and trigger multiple on-chip resources (ADC, DAC, Timers, etc.)
- · Asynchronous output may be used to wake from low-power states

Parameter	Symbol	Test Condition	Min	Тур	Мах	Unit
Note:						
	e. For example, where by the specified amount	I_{DD} is specified and the mode is not m	nutually exclu	ısive, enablir	ng the function	ons increa-
2. Includes supply curr	rent from internal LDO r	regulator, supply monitor, and High Fre	equency Osc	cillator.		
3. Includes supply curr	rent from internal LDO r	regulator, supply monitor, and Low Fre	equency Osc	illator.		
4. ADC0 power exclud	les internal reference su	upply current.				
5. The internal referen depend on sampling		d when operating the ADC in low pow	ver mode. To	tal ADC + R	eference cur	rent will
0.000		nd not including external load on pin.				

4.1.3 Reset and Supply Monitor

Parameter	Symbol	Test Condition	Min	Тур	Мах	Unit
VDD Supply Monitor Threshold	V _{VDDM}		1.95	2.05	2.15	V
Power-On Reset (POR) Threshold	V _{POR}	Rising Voltage on VDD	_	1.4	_	V
		Falling Voltage on VDD	0.75	—	1.36	V
VDD Ramp Time	t _{RMP}	Time to V _{DD} > 2.2 V	10	_	_	μs
Reset Delay from POR	t _{POR}	Relative to V _{DD} > V _{POR}	3	10	31	ms
Reset Delay from non-POR source	t _{RST}	Time between release of reset source and code execution	_	50	-	μs
RST Low Time to Generate Reset	t _{RSTL}		15	_	_	μs
Missing Clock Detector Response Time (final rising edge to reset)	t _{MCD}	F _{SYSCLK} >1 MHz	_	0.625	1.2	ms
Missing Clock Detector Trigger Frequency	F _{MCD}		_	7.5	13.5	kHz
VDD Supply Monitor Turn-On Time	t _{MON}		-	2	—	μs

Table 4.3. Reset and Supply Monitor

Table 4.9. ADC

Parameter	Symbol	Test Condition	Min	Тур	Max	Unit
Resolution	N _{bits}	12 Bit Mode		12		Bits
		10 Bit Mode		10		Bits
Throughput Rate	f _S	10 Bit Mode	_	_	1.125	Msps
(High Speed Mode)						
Throughput Rate	f _S	12 Bit Mode	_	_	340	ksps
(Low Power Mode)		10 Bit Mode	_	_	360	ksps
Tracking Time	t _{TRK}	High Speed Mode	230	_	_	ns
		Low Power Mode	450	_	_	ns
Power-On Time	t _{PWR}		1.2	_	_	μs
SAR Clock Frequency	f _{SAR}	High Speed Mode	_	_	18	MHz
		Low Power Mode	_	_	12.25	MHz
Conversion Time ¹	t _{CNV}	12-Bit Conversion,		2.0		μs
		SAR Clock = 6.125 MHz,				
		System Clock = 49 MHz				
		10-Bit Conversion,		0.658		μs
		SAR Clock = 16.33 MHz,				
		System Clock = 49 MHz				
Sample/Hold Capacitor	C _{SAR}	Gain = 1		5.2	_	pF
		Gain = 0.75	_	3.9	_	pF
		Gain = 0.5	_	2.6	_	pF
		Gain = 0.25	_	1.3	_	pF
Input Pin Capacitance	C _{IN}			20	_	pF
Input Mux Impedance	R _{MUX}			550	_	Ω
Voltage Reference Range	V _{REF}		1	_	V _{IO}	V
Input Voltage Range ²	V _{IN}		0	_	V _{REF} / Gain	V
Power Supply Rejection Ratio	PSRR _{ADC}	At 1 kHz	_	66	_	dB
		At 1 MHz		43	_	dB

EFM8BB3 Data Sheet Electrical Specifications

Parameter	Symbol	Test Condition	Min	Тур	Мах	Unit		
Note: 1. Conversion Time does not include Tracking Time. Total Conversion Time is: Total Conversion Time = [RPT × (ADTK + NUMBITS + 1) × T(SARCLK)] + (T(ADCCLK) × 4)								
where RPT is the number of co 2. Absolute input pin voltage is lim	nversions re ited by the \	presented by the ADRPT field and AD	OCCLK is the					

4.1.13 Comparators

Parameter	Symbol	Test Condition	Min	Тур	Max	Unit
Response Time, CPMD = 00	t _{RESP0}	+100 mV Differential	_	100	_	ns
(Highest Speed)		-100 mV Differential	_	150	_	ns
Response Time, CPMD = 11 (Low-	t _{RESP3}	+100 mV Differential	_	1.5	_	μs
est Power)		-100 mV Differential	_	3.5	_	μs
Positive Hysteresis	HYS _{CP+}	CPHYP = 00	_	0.4	_	mV
Mode 0 (CPMD = 00)		CPHYP = 01	_	8	_	mV
		CPHYP = 10	_	16	_	mV
		CPHYP = 11	_	32	_	mV
Negative Hysteresis	HYS _{CP-}	CPHYN = 00	_	-0.4	_	mV
Mode 0 (CPMD = 00)		CPHYN = 01	_	-8	_	mV
		CPHYN = 10	_	-16	_	mV
		CPHYN = 11	_	-32	_	mV
Positive Hysteresis	HYS _{CP+}	CPHYP = 00	_	0.5	_	mV
Mode 1 (CPMD = 01)		CPHYP = 01	—	6	_	mV
		CPHYP = 10	_	12	_	mV
		CPHYP = 11	_	24	_	mV
Negative Hysteresis	HYS _{CP-}	CPHYN = 00	—	-0.5	_	mV
Mode 1 (CPMD = 01)		CPHYN = 01	_	-6	_	mV
		CPHYN = 10	—	-12	_	mV
		CPHYN = 11	—	-24	_	mV
Positive Hysteresis	HYS _{CP+}	CPHYP = 00	_	0.7	_	mV
Mode 2 (CPMD = 10)		CPHYP = 01	_	4.5	_	mV
		CPHYP = 10	_	9	_	mV
		CPHYP = 11	_	18	_	mV
Negative Hysteresis	HYS _{CP-}	CPHYN = 00	_	-0.6	_	mV
Mode 2 (CPMD = 10)		CPHYN = 01	_	-4.5	_	mV
		CPHYN = 10	_	-9	_	mV
		CPHYN = 11	_	-18	_	mV
Positive Hysteresis	HYS _{CP+}	CPHYP = 00	_	1.5	_	mV
Mode 3 (CPMD = 11)		CPHYP = 01		4	_	mV
		CPHYP = 10	_	8	_	mV
		CPHYP = 11		16	_	mV

Table 4.13. Comparators

Parameter	Symbol	Test Condition	Min	Тур	Max	Unit
Negative Hysteresis	HYS _{CP-}	CPHYN = 00	_	-1.5	_	mV
Mode 3 (CPMD = 11)		CPHYN = 01	—	-4	_	mV
		CPHYN = 10	_	-8	_	mV
		CPHYN = 11	—	-16	—	mV
Input Range (CP+ or CP-)	V _{IN}		-0.25	_	V _{IO} +0.25	V
Input Pin Capacitance	C _{CP}		—	7.5	—	pF
Internal Reference DAC Resolution	N _{bits}			6	1	bits
Common-Mode Rejection Ratio	CMRR _{CP}		_	70	_	dB
Power Supply Rejection Ratio	PSRR _{CP}		_	72	_	dB
Input Offset Voltage	V _{OFF}	T _A = 25 °C	-10	0	10	mV
Input Offset Tempco	TC _{OFF}		_	3.5	_	μV/°

4.1.14 Configurable Logic

Table 4.14. Configurable Logic

Parameter	Symbol	Test Condition	Min	Тур	Мах	Unit
Propagation Delay	t _{DLY}	Through single CLU	—	_	35.3	ns
		Using an external pin				
		Through single CLU	—	3	—	ns
		Using an internal connection				
Clocking Frequency F _{CLK}		1 or 2 CLUs Cascaded	—	—	73.5	MHz
		3 or 4 CLUs Cascaded			36.75	MHz

4.1.15 Port I/O

Table 4.15. Port I/O

Parameter	Symbol	Test Condition	Min	Тур	Мах	Unit
Output High Voltage (High Drive)	V _{OH}	I _{OH} = -7 mA, V _{IO} ≥ 3.0 V	V _{IO} - 0.7	_	—	V
		I_{OH} = -3.3 mA, 2.2 V ≤ V _{IO} < 3.0 V	V _{IO} x 0.8	_	_	V
		I_{OH} = -1.8 mA, 1.71 V \leq V _{IO} < 2.2 V				
Output Low Voltage (High Drive)	V _{OL}	I _{OL} = 13.5 mA, V _{IO} ≥ 3.0 V		_	0.6	V
		I_{OL} = 7 mA, 2.2 V ≤ V_{IO} < 3.0 V			V _{IO} x 0.2	V
		I_{OL} = 3.6 mA, 1.71 V \leq V _{IO} < 2.2 V				
Output High Voltage (Low Drive)	V _{OH}	I _{OH} = -4.75 mA, V _{IO} ≥ 3.0 V	V _{IO} - 0.7	_	_	V
		I_{OH} = -2.25 mA, 2.2 V ≤ V _{IO} < 3.0 V	V _{IO} x 0.8	_	—	V
		I_{OH} = -1.2 mA, 1.71 V \leq V _{IO} < 2.2 V				
Output Low Voltage (Low Drive)	V _{OL}	I_{OL} = 6.5 mA, $V_{IO} \ge 3.0$ V	—	—	0.6	V
		I_{OL} = 3.5 mA, 2.2 V ≤ V_{IO} < 3.0 V	—	_	V _{IO} x 0.2	V
		I_{OL} = 1.8 mA, 1.71 V \leq V _{IO} < 2.2 V				
Input High Voltage	V _{IH}		0.7 x	_	—	V
			V _{IO}			
Input Low Voltage	V _{IL}		—	_	0.3 x	V
					V _{IO}	
Pin Capacitance	C _{IO}		—	7	—	pF
Weak Pull-Up Current	I _{PU}	V _{DD} = 3.6	-30	-20	-10	μA
(V _{IN} = 0 V)						
Input Leakage (Pullups off or Ana- log)	I _{LK}	GND < V _{IN} < V _{IO}	-1.1	_	4	μA
Input Leakage Current with VIN	I _{LK}	$V_{IO} < V_{IN} < V_{IO} + 2.5 V$	0	5	150	μA
above V _{IO}		Any pin except P3.0, P3.1, P3.2, or P3.3				

6. Pin Definitions

6.1 EFM8BB3x-QFN32 Pin Definitions

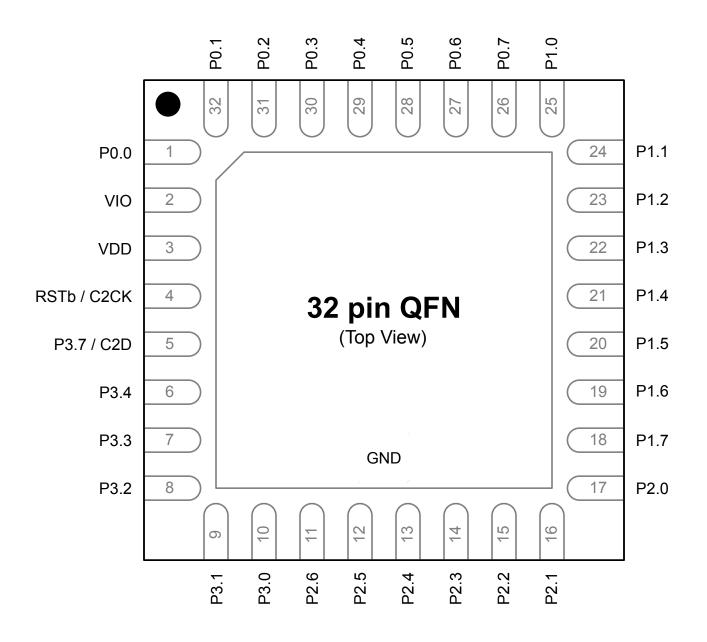


Figure 6.1. EFM8BB3x-QFN32 Pinout

Pin Number	Pin Name	Description	Crossbar Capability	Additional Digital Functions	Analog Functions
23	P1.2	Multifunction I/O	Yes	P1MAT.2	ADC0.8
				CLU0A.13	CMP0P.8
				CLU1A.11	CMP0N.8
				CLU2B.10	
				CLU3A.12	
24	P1.1	Multifunction I/O	Yes	P1MAT.1	ADC0.7
				CLU0B.12	CMP0P.7
				CLU1B.10	CMP0N.7
				CLU2A.11	
				CLU3B.13	
25	P1.0	Multifunction I/O	Yes	P1MAT.0	ADC0.6
				CLU1OUT	CMP0P.6
				CLU0A.12	CMP0N.6
				CLU1A.10	CMP1P.1
				CLU2A.10	CMP1N.1
				CLU3B.12	
26	P0.7	Multifunction I/O	Yes	P0MAT.7	ADC0.5
				INT0.7	CMP0P.5
				INT1.7	CMP0N.5
				CLU0B.11	CMP1P.0
				CLU1B.9	CMP1N.0
				CLU3A.11	
27	P0.6	Multifunction I/O	Yes	P0MAT.6	ADC0.4
				CNVSTR	CMP0P.4
				INT0.6	CMP0N.4
				INT1.6	
				CLU0A.11	
				CLU1B.8	
				CLU3A.10	
28	P0.5	Multifunction I/O	Yes	P0MAT.5	ADC0.3
				INT0.5	CMP0P.3
				INT1.5	CMP0N.3
				UART0_RX	
				CLU0B.10	
				CLU1A.9	
				CLU3B.11	

Pin Number	Pin Name	Description	Crossbar Capability	Additional Digital Functions	Analog Functions
29	P0.4	Multifunction I/O	Yes	P0MAT.4	ADC0.2
				INT0.4	CMP0P.2
				INT1.4	CMP0N.2
				UART0_TX	
				CLU0A.10	
				CLU1A.8	
				CLU3B.10	
30	P0.3	Multifunction I/O	Yes	P0MAT.3	XTAL2
				EXTCLK	
				INT0.3	
				INT1.3	
				CLU0B.9	
				CLU2B.9	
				CLU3A.9	
31	P0.2	Multifunction I/O	Yes	P0MAT.2	XTAL1
				INT0.2	ADC0.1
				INT1.2	CMP0P.1
				CLU0OUT	CMP0N.1
				CLU0A.9	
				CLU2B.8	
				CLU3A.8	
32	P0.1	Multifunction I/O	Yes	P0MAT.1	ADC0.0
				INT0.1	CMP0P.0
				INT1.1	CMP0N.0
				CLU0B.8	AGND
				CLU2A.9	
				CLU3B.9	
Center	GND	Ground			

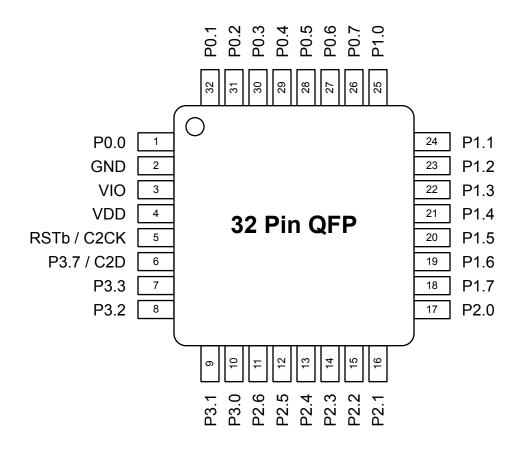


Figure 6.2. EFM8BB3x-QFP32 Pinout

Table 6.2.	Pin Definitions	for EFM8BB3x-QFP32
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Pin Number	Pin Name	Description	Crossbar Capability	Additional Digital Functions	Analog Functions
1	P0.0	Multifunction I/O	Yes	P0MAT.0	VREF
				INT0.0	
				INT1.0	
				CLU0A.8	
				CLU2A.8	
				CLU3B.8	
2	GND	Ground			
3	VIO	I/O Supply Power Input			
4	VDD	Supply Power Input			
5	RSTb /	Active-low Reset /			
	C2CK	C2 Debug Clock			

Pin Number	Pin Name	Description	Crossbar Capability	Additional Digital Functions	Analog Functions
6	P3.7 /	Multifunction I/O /			
	C2D	C2 Debug Data			
7	P3.3	Multifunction I/O			DAC3
8	P3.2	Multifunction I/O			DAC2
9	P3.1	Multifunction I/O			DAC1
10	P3.0	Multifunction I/O			DAC0
11	P2.6	Multifunction I/O			ADC0.19
					CMP1P.8
					CMP1N.8
12	P2.5	Multifunction I/O		CLU3OUT	ADC0.18
					CMP1P.7
					CMP1N.7
13	P2.4	Multifunction I/O			ADC0.17
					CMP1P.6
					CMP1N.6
14	P2.3	Multifunction I/O	Yes	P2MAT.3	ADC0.16
				CLU1B.15	CMP1P.5
				CLU2B.15	CMP1N.5
				CLU3A.15	
15	P2.2	Multifunction I/O	Yes	P2MAT.2	ADC0.15
				CLU2OUT	CMP1P.4
				CLU1A.15	CMP1N.4
				CLU2B.14	
				CLU3A.14	
16	P2.1	Multifunction I/O	Yes	P2MAT.1	ADC0.14
				I2C0_SCL	CMP1P.3
				CLU1B.14	CMP1N.3
				CLU2A.15	
				CLU3B.15	
17	P2.0	Multifunction I/O	Yes	P2MAT.0	CMP1P.2
				I2C0_SDA	CMP1N.2
				CLU1A.14	
				CLU2A.14	
				CLU3B.14	

Pin Number	Pin Name	Description	Crossbar Capability	Additional Digital Functions	Analog Functions
30	P0.3	Multifunction I/O	Yes	P0MAT.3	XTAL2
				EXTCLK	
				INT0.3	
				INT1.3	
				CLU0B.9	
				CLU2B.9	
				CLU3A.9	
31	P0.2	Multifunction I/O	Yes	P0MAT.2	XTAL1
				INT0.2	ADC0.1
				INT1.2	CMP0P.1
				CLU0OUT	CMP0N.1
				CLU0A.9	
				CLU2B.8	
				CLU3A.8	
32	P0.1	Multifunction I/O	Yes	P0MAT.1	ADC0.0
				INT0.1	CMP0P.0
				INT1.1	CMP0N.0
				CLU0B.8	AGND
				CLU2A.9	
				CLU3B.9	

Pin Number	Pin Name	Description	Crossbar Capability	Additional Digital Functions	Analog Functions
2	P0.2	Multifunction I/O	Yes	P0MAT.2	XTAL1
				INT0.2	ADC0.1
				INT1.2	CMP0P.1
				CLU0OUT	CMP0N.1
				CLU0A.9	
				CLU2B.8	
				CLU3A.8	
3	P0.1	Multifunction I/O	Yes	P0MAT.1	ADC0.0
				INT0.1	CMP0P.0
				INT1.1	CMP0N.0
				CLU0B.8	AGND
				CLU2A.9	
				CLU3B.9	
4	P0.0	Multifunction I/O	Yes	P0MAT.0	VREF
				INT0.0	
				INT1.0	
				CLU0A.8	
				CLU2A.8	
				CLU3B.8	
5	GND	Ground			
6	VDD / VIO	Supply Power Input			
7	RSTb /	Active-low Reset /			
	C2CK	C2 Debug Clock			
8	P3.0 /	Multifunction I/O /			
	C2D	C2 Debug Data			
9	P2.3	Multifunction I/O	Yes	P2MAT.3	DAC3
				CLU1B.15	
				CLU2B.15	
				CLU3A.15	
10	P2.2	Multifunction I/O	Yes	P2MAT.2	DAC2
				CLU1A.15	
				CLU2B.14	
				CLU3A.14	

Pin Number	Pin Name	Description	Crossbar Capability	Additional Digital Functions	Analog Functions
24	P0.4	Multifunction I/O	Yes	P0MAT.4	ADC0.2
				INT0.4	CMP0P.2
				INT1.4	CMP0N.2
				UART0_TX	
				CLU0A.10	
				CLU1A.8	
				CLU3B.10	

9.2 QFN24 PCB Land Pattern

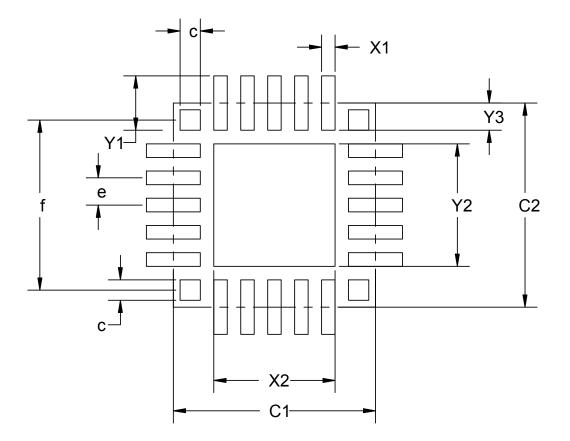


Figure 9.2. QFN24 PCB Land Pattern Drawing

Table 9.2. QFN24 PCB Land Pattern Dimensions

Dimension	Min	Мах		
C1	3.00			
C2	3.00			
е	0.4 REF			
X1	0.20			
X2	1.80			
Y1	0.80			
Y2	1.80			
Y3	0.4			
f	2.50 REF			
с	0.25 0.35			

Dimension	Min	Мах			
Note:					
1. All dimensions shown are in millimeters	(mm) unless otherwise noted.				
2. Dimensioning and Tolerancing is per the	ANSI Y14.5M-1994 specification.				
3. This Land Pattern Design is based on the IPC-SM-782 guidelines.					
4. All metal pads are to be non-solder mask defined (NSMD). Clearance between the solder mask and the metal pad is to be 60 μm minimum, all the way around the pad.					
5. A stainless steel, laser-cut and electro-polished stencil with trapezoidal walls should be used to assure good solder paste release.					
6. The stencil thickness should be 0.125 mm (5 mils).					
7. The ratio of stencil aperture to land pad size should be 1:1 for all perimeter pads.					
8. A 2 x 1 array of 0.7 mm x 1.6 mm opening	igs on a 0.9 mm pitch should be used for the	center pad.			
9. A No-Clean, Type-3 solder paste is reco	mmended.				

10. The recommended card reflow profile is per the JEDEC/IPC J-STD-020 specification for Small Body Components.

9.3 QFN24 Package Marking

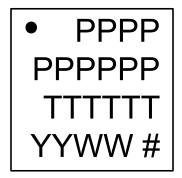


Figure 9.3. QFN24 Package Marking

The package marking consists of:

- PPPPPPP The part number designation.
- TTTTTT A trace or manufacturing code.
- YY The last 2 digits of the assembly year.
- WW The 2-digit workweek when the device was assembled.
- # The device revision (A, B, etc.).

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